







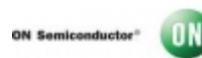

	<h2 style="color: red;">H11A817A3SD</h2>
 <p>Image may be representation. See specs for product details.</p>	Hersteller-Teilenummer: H11A817A3SD
	Hersteller / Marke: Fairchild/ON Semiconductor
	Teil der Beschreibung: OPTOISO 5.3KV TRANSISTOR 4SMD
	Datenblätter:  H11A817A3SD.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 25445 pcs Stock Available.
Liefern von: Hong Kong	
Versandweg: DHL/Fedex/TNT/UPS/EMS	

Spezifikationen

Teilenummer	H11A817A3SD
Hersteller	Fairchild/ON Semiconductor
Beschreibung	OPTOISO 5.3KV TRANSISTOR 4SMD
Kategorie	Isolatoren > Optoisolatoren - Transistor, Photovoltaik-
Teilstatus	25445 pcs Stock
Serie	-
Eingabetyp	DC
Betriebstemperatur	-55°C ~ 100°C
Befestigungsart	Surface Mount
Ausgabebetyp	Transistor
Anzahl der Kanäle	1
Verpackung / Gehäuse	4-SMD, Gull Wing
Supplier Device-Gehäuse	4-SMD
Strom - Ausgang / Kanal	50mA
Spannung - Isolation	5300Vrms
Aufstieg / Fallzeit (Typ)	2.4µs, 2.4µs
Spannung - Ausgabe (max)	70V
Spannung - Vorwärts (Vf) (Typ)	1.2V
Strom - DC Vorwärts (If) (Max)	50mA
Gleichstrom-Übertragungsverhältnis (min)	80% @ 5mA
Stromübertragungsverhältnis (max)	160% @ 5mA
Ein- / Ausschaltzeit (Typ)	-
VCE Sättigung (max)	200mV
Verpackung	Tape & Reel (TR)




















H11A817A3SD ist neu im Original, Suche H11A817A3SD Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie H11A817A3SD Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage H11A817A3SD: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>H11A817ASD AMI Semiconductor / ON Semiconductor OPTOISO 5.3KV TRANSISTOR 4SMD</p>	 <p>H11A817A3S Fairchild/ON Semiconductor OPTOISO 5.3KV TRANSISTOR 4SMD</p>	 <p>H11A817AS Fairchild/ON Semiconductor OPTOISO 5.3KV TRANSISTOR 4SMD</p>	 <p>H11A817A300W Fairchild/ON Semiconductor OPTOISO 5.3KV TRANSISTOR 4DIP</p>
 <p>H11A817A3SD AMI Semiconductor / ON Semiconductor OPTOISO 5.3KV TRANSISTOR 4SMD</p>	 <p>H11A817ASD Fairchild/ON Semiconductor OPTOISO 5.3KV TRANSISTOR 4SMD</p>	 <p>H11A817A3S AMI Semiconductor / ON Semiconductor OPTOISO 5.3KV TRANSISTOR 4SMD</p>	 <p>H11A817A300W AMI Semiconductor / ON Semiconductor OPTOISO 5.3KV TRANSISTOR 4DIP</p>

heiße Teile

Mehr

 H11A5SVM	 H11A5SVM	 H11A5TVM	D H11A5TVM	 H11A617A3SD
 H11A617A3SD	 H11A617B	D H11A617B	 H11A617B300	 H11A617B300
 H11A617B3SD	 H11A617B3SD	 H11A617BS	 H11A617BS	 H11A617BSD
D H11A617BSD	 H11A617CSD	 H11A617CSD	 H11A617D3SD	 H11A617D3SD
 H11A814C	 H11A817A	 H11A817A	 H11A817A.3SD	 H11A817A3SD
 H11A817ASD	 H11A817ASD	D H11A817B	 H11A817B	 H11A817B.3SD
 H11A817B300	D H11A817B300	 H11A817B3SD	 H11A817B3SD	 H11A817BSD
 H11A817BSD	 H11A817BW	 H11A817BW	 H11A817C	 H11A817C
 H11A817C300	 H11A817C300	 H11A817C3SD	D H11A817C3SD	 H11A817CSD
 H11A817CSD	 H11A817CW	 H11A817CW	 H11A817SD	 H11A817SD

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited